FAIRCHILD

SEMICONDUCTOR

NC7ST00 TinyLogic[™] HST 2-Input NAND Gate

General Description

The NC7ST00 is a single 2-Input high performance CMOS NAND Gate, with TTL-compatible inputs. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation. ESD protection diodes inherently guard both inputs and output with respect to the V_{CC} and GND rails. High gain circuitry offers high noise immunity and reduced sensitivity to input edge rate. The TTL-compatible inputs facilitate TTL to NMOS/CMOS interfacing. Device performance is similar to MM74HCT but with 1/2 the output current drive of HC/HCT.

February 1997 Revised April 2002

Features

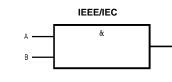
- Space saving SOT23 or SC70 5-lead package
- Ultra small MicroPak[™] leadless package
- High Speed; t_{PD} < 7 ns typ, V_{CC} = 5V, C_L = 15 pF
- \blacksquare Low Quiescent Power; I_{CC} < 1 μA typ, V_{CC} = 5.5V
- Balanced Output Drive; 2 mA I_{OL}, -2 mA I_{OH}
- TTL-compatible inputs

Ordering Code:								
Order	Package	Product Code						
Number	Number	Top Mark						

Number	Number	Top Mark	Package Description	Supplied As
NC7ST00M5X	MA05B	8S00	5-Lead SOT23, JEDEC MO-178, 1.6mm	3k Units on Tape and Reel
NC7ST00P5X	MAA05A	Т00	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3k Units on Tape and Reel
NC7ST00L6X	MAC06A	E3	6-Lead MicroPak, 1.0mm Wide	5k Units on Tape and Reel

Logic Symbol

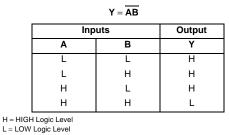


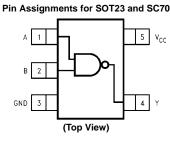


Pin Descriptions

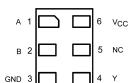
Pin Names	Description
А, В	Inputs
Y	Output
NC	No Connect

Function Table





Pad Assignments for MicroPak





(Top Thru View)

TinyLogic™ and MicroPak™ are trademarks of Fairchild Semiconductor Corporation.

© 2002 Fairchild Semiconductor Corporation DS012181

Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Input Diode Current (IIK)	
V _{IN} < -0.5V	–20 mA
$V_{IN} \ge V_{CC} + 0.5V$	+20 mA
DC Input Voltage V _{IN}	-0.5V to V _{CC} + 0.5V
DC Output Diode Current (I _{OK})	
$V_{OUT} < -0.5V$	–20 mA
$V_{OUT} > V_{CC} + 0.5V$	+20 mA
Output Voltage (V _{OUT})	–0.5V to V_{CC} + 0.5V
DC Output Source or	
Sink Current (I _{OUT})	±12.5 mA
DC V _{CC} or Ground Current per	
Supply Pin (I _{CC} or I _{GND})	±25 mA
Storage Temperature (T _{STG})	-65°C to +150°C
Junction Temperature (T _J)	150°C
Lead Temperature (T _L);	
(Soldering, 10 seconds)	260°C
Power Dissipation (P _D) @ +85°C	
SOT23-5	200 mW
SC70-5	150 mW

Recommended Operating Conditions (Note 2)

Supply Voltage	4.5V to 5.5V
Input Voltage (V _{IN})	0.0V to V_{CC}
Output Voltage (V _{OUT})	0V to V_{CC}
Operating Temperature (T _A)	$-40^{\circ}C$ to $+85^{\circ}C$
Input Rise and Fall Time (t_r, t_f)	
$V_{CC} = 5.0V$	0 to 500 ns
Thermal Resistance (θ_{JA})	
SOT23-5	300°C/W
SC70-5	425°C/W

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the design is reliable over its power supply, temperature, and output/input loading variables Fairchild does not reommend operation of circuits outside the databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

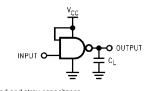
DC Electrical Characteristics

Symbol	Parameter	V _{cc} (V)	$T_A = +25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ Units Conditions	$T_A = +25^{\circ}C$ T_A		$T_A = +25^{\circ}C$		Conditions	
			Min	Тур	Max	Min	Max	onita	Contaciona
V _{IH}	HIGH Level Input Voltage	4.5–5.5	2.0			2.0		V	
VIL	LOW Level Input Voltage	4.5–5.5			0.8		0.8	V	
V _{OH}	HIGH Level Output Voltage	4.5	4.4	4.5		4.4			$I_{OH} = -20 \ \mu A$
		4.5	4.18	4.35		4.13		V	$I_{OH} = -2 \text{ mA}$
									$V_{IN} = V_{IL}$
V _{OL}	LOW Level Output Voltage	4.5		0	0.1		0.1		$I_{OL} = 20 \ \mu A$
		4.5		0.10	0.26		0.33	V	$I_{OL} = 2 \text{ mA}$
									$V_{IN} = V_{IH}$
I _{IN}	Input Leakage Current	5.5			±0.1		±1.0	μΑ	$0 \le V_{IN} \le 5.5V$
I _{CC}	Quiescent Supply Current	5.5			1.0		10.0	μΑ	$V_{IN} = V_{CC}$ or GND
ICCT	I _{CC} per Input	5.5			2.0		2.9	mA	One Input $V_{IN} = 0.5V$ or 2.4V,
									Other Input V _{CC} or GND

Symbol	Parameter	V _{CC}	T _A = +25°C			$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units	Conditions	Figure
Symbol		(V)	Min	Тур	Max	Min	Max	Units	Conditions	Number
t _{PLH} ,	Propagation Delay	5.0		3.4	12				$C_L = 15 \text{ pF}$ $C_L = 50 \text{ pF}$	Figures 1, 3
t _{PHL}				6.3	17					
		4.5		6.0	16		20			
		-		11.5	27		31	ns		
		5.5		4.1	14		18			
	-		11.2	26		30				
t _{TLH} ,	Output Transition Time	5.0		4	10			ns	$C_L = 15 \text{ pF}$	
t _{THL}		4.5		11	25		31	-	C = 50 pF	Figures 1, 3
		5.5		10	21		26	ns	$C_L = 50 \text{ pF}$	1,0
CIN	Input Capacitance	Open		2	10			pF		
C _{PD}	Power Dissipation Capacitance	5.0		6				pF	(Note 3)	Figure 2

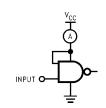
Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current. Current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 2). CPD is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD})(V_{CC})(f_{IN}) + (I_{CCstatic}).

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR = 1.0 MHz; t_w = 500 ns

FIGURE 1. AC Test Circuit



Input = AC Waveform; PRR = variable; Duty Cycle = 50% FIGURE 2. I_{CCD} Test Circuit

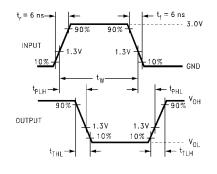
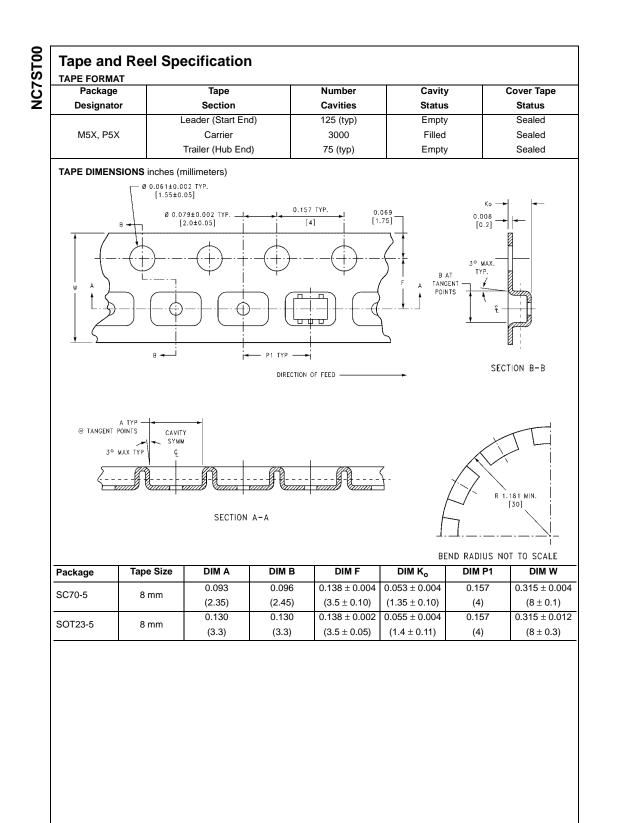
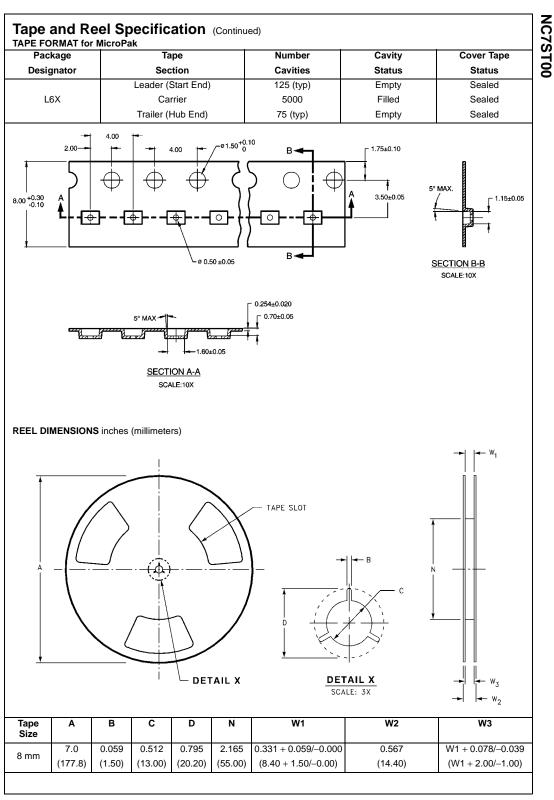


FIGURE 3. AC Waveforms





www.fairchildsemi.com

5

